## MPF4392, MPF4393

## JFET Switching Transistors

## N-Channel - Depletion

## Features

- $\mathrm{Pb}-$ Free Packages are Available*

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Drain-Source Voltage | $\mathrm{V}_{\mathrm{DS}}$ | 30 | Vdc |
| Drain-Gate Voltag | $\mathrm{V}_{\mathrm{DG}}$ | 30 | Vdc |
| Gate-Source Voltage | $\mathrm{V}_{\mathrm{GS}}$ | 30 | Vdc |
| Forward Gate Current | $\mathrm{I}_{\mathrm{G}(\mathrm{f})}$ | 50 | mAdc |
| Total Device Dissipation <br> $@ \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ <br> Derate above $25^{\circ} \mathrm{C}$ | P | 350 | mW |
| $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |  |  |  |
| Operating and Storage Channel <br> Temperature Range | $\mathrm{T}_{\text {channel }}$, <br> $\mathrm{T}_{\text {stg }}$ | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor ${ }^{\circledR}$
http://onsemi.com


ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :--- | :---: | :---: |
| MPF4392 | TO-92 | 1000 Units / Bulk |
| MPF4392G | TO-92 <br> $($ Pb-Free $)$ | 1000 Units / Bulk |
| MPF4393 | TO-92 | 1000 Units / Bulk |
| MPF4393G | TO-92 <br> (Pb-Free) | 1000 Units / Bulk |
| MPF4393RLRP | TO-92 | 1000 / Ammo Box |
| MPF4393RLRPG | TO-92 <br> (Pb-Free) | 1000 / Ammo Box |

ELECTRICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)

| Characteristic |  | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS |  |  |  |  |  |  |
| Gate-Source Breakdown Voltage $\left(I_{G}=-1.0 \mu \mathrm{Adc}, \mathrm{V}_{\mathrm{DS}}=0\right)$ |  | $\mathrm{V}_{\text {(BR) GSS }}$ | 30 | - | - | Vdc |
| $\begin{aligned} & \text { Gate Reverse Current } \\ & \left(\mathrm{V}_{\mathrm{GS}}=-15 \mathrm{Vdc}, \mathrm{~V}_{\mathrm{DS}}=0\right) \\ & \left(\mathrm{V}_{\mathrm{GS}}=-15 \mathrm{Vdc}, \mathrm{~V}_{\mathrm{DS}}=0, \mathrm{~T}_{\mathrm{A}}=100^{\circ} \mathrm{C}\right) \end{aligned}$ |  | IGSS | - | - | $\begin{aligned} & 1.0 \\ & 0.2 \end{aligned}$ | nAdc <br> $\mu$ Adc |
| $\begin{aligned} & \text { Drain-Cutoff Current } \\ & \left(\mathrm{V}_{\mathrm{DS}}=15 \mathrm{Vdc}, \mathrm{~V}_{\mathrm{GS}}=-12 \mathrm{Vdc}\right) \\ & \left(\mathrm{V}_{\mathrm{DS}}=15 \mathrm{Vdc}, \mathrm{~V}_{\mathrm{GS}}=-12 \mathrm{Vdc}, \mathrm{~T}_{\mathrm{A}}=100^{\circ} \mathrm{C}\right) \end{aligned}$ |  | $\mathrm{I}_{\mathrm{D} \text { (off) }}$ | - | - | $\begin{aligned} & 1.0 \\ & 1.0 \end{aligned}$ | nAdc <br> $\mu \mathrm{Adc}$ |
| Gate Source Voltage $\left(\mathrm{V}_{\mathrm{DS}}=15 \mathrm{Vdc}, \mathrm{I}_{\mathrm{D}}=10 \mathrm{nAdc}\right)$ | MPF4392 <br> MPF4393 | $\mathrm{V}_{\mathrm{GS}}$ | $\begin{aligned} & -2.0 \\ & -0.5 \end{aligned}$ | - | $\begin{aligned} & -5.0 \\ & -3.0 \end{aligned}$ | Vdc |

ON CHARACTERISTICS

| Zero-Gate-Voltage Drain Current (Note 1) $\left(V_{D S}=15 \mathrm{Vdc}, \mathrm{V}_{\mathrm{GS}}=0\right)$ | MPF4392 <br> MPF4393 | IDSS | 25 5.0 | - | $\begin{aligned} & 75 \\ & 30 \end{aligned}$ | mAdc |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Drain-Source On-Voltage $\left(\mathrm{I}_{\mathrm{D}}=6.0 \mathrm{mAdc}, \mathrm{V}_{\mathrm{GS}}=0\right)$ $\left(\mathrm{I}_{\mathrm{D}}=3.0 \mathrm{mAdc}, \mathrm{V}_{\mathrm{GS}}=0\right)$ | MPF4392 <br> MPF4393 | $\mathrm{V}_{\mathrm{DS} \text { (on) }}$ |  | - | $\begin{aligned} & 0.4 \\ & 0.4 \end{aligned}$ | Vdc |
| Static Drain-Source On Resistance $\left(\mathrm{I}_{\mathrm{D}}=1.0 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{GS}}=0\right)$ | MPF4392 <br> MPF4393 | ${ }^{\text {r }}$ S(on) | - | - | $\begin{gathered} 60 \\ 100 \end{gathered}$ | $\Omega$ |

SMALL-SIGNAL CHARACTERISTICS

| Forward Transfer Admittance $\begin{aligned} & \left(\mathrm{V}_{\mathrm{DS}}=15 \mathrm{Vdc}, \mathrm{I}_{\mathrm{D}}=25 \mathrm{mAdc}, \mathrm{f}=1.0 \mathrm{kHz}\right) \\ & \left(\mathrm{V}_{\mathrm{DS}}=15 \mathrm{Vdc}, \mathrm{I}_{\mathrm{D}}=5.0 \mathrm{mAdc}, \mathrm{f}=1.0 \mathrm{kHz}\right) \end{aligned}$ | $\begin{aligned} & \text { MPF4392 } \\ & \text { MPF4393 } \end{aligned}$ | $\left\|y_{\text {fs }}\right\|$ | - | $\begin{aligned} & 17 \\ & 12 \end{aligned}$ | - | mmhos |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Drain-Source "ON" Resistance $\left(V_{G S}=0, I_{D}=0, f=1.0 \mathrm{kHz}\right)$ | MPF4392 <br> MPF4393 | $\mathrm{r}_{\mathrm{ds}(\mathrm{on})}$ | - | - | $\begin{gathered} 60 \\ 10 \end{gathered}$ | $\Omega$ |
| Input Capacitance ( $\mathrm{V}_{\mathrm{GS}}=15 \mathrm{Vdc}, \mathrm{V}_{\mathrm{DS}}=0, \mathrm{f}=1.0 \mathrm{MHz}$ ) |  | $\mathrm{C}_{\text {iss }}$ | - | 6.0 | 10 | pF |
| $\begin{aligned} & \text { Reverse Transfer Capacitance } \\ & \left(V_{G S}=12 \mathrm{Vdc}, V_{D S}=0, f=1.0 \mathrm{MHz}\right) \\ & \left(V_{D S}=15 \mathrm{Vdc}, I_{D}=10 \mathrm{mAdc}, \mathrm{f}=1.0 \mathrm{MHz}\right) \end{aligned}$ |  | $\mathrm{C}_{\text {rss }}$ | - | $\begin{aligned} & 2.5 \\ & 3.2 \end{aligned}$ | 3.5 | pF |

SWITCHING CHARACTERISTICS

| Rise Time (See Figure 2) $\begin{aligned} & \left(\mathrm{l}_{\mathrm{D}(\mathrm{on})}=6.0 \mathrm{mAdc}\right) \\ & \left(\mathrm{I}_{\mathrm{D}(\mathrm{on})}=3.0 \mathrm{mAdc}\right) \end{aligned}$ | $\begin{aligned} & \text { MPF4392 } \\ & \text { MPF4393 } \end{aligned}$ | $\mathrm{t}_{\mathrm{r}}$ | - | $\begin{aligned} & 2.0 \\ & 2.5 \end{aligned}$ | $\begin{aligned} & 5.0 \\ & 5.0 \end{aligned}$ | ns |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Fall Time (See Figure 4) $\begin{aligned} & \left(\mathrm{V}_{\mathrm{GS} \text { (off) }}=7.0 \mathrm{Vdc}\right) \\ & \left(\mathrm{V}_{\mathrm{GS} \text { (off) })}=5.0 \mathrm{Vdc}\right) \end{aligned}$ | MPF4392 <br> MPF4393 | $\mathrm{t}_{\mathrm{f}}$ | - | $\begin{aligned} & 15 \\ & 29 \end{aligned}$ | $\begin{aligned} & 20 \\ & 35 \end{aligned}$ | ns |
| $\begin{aligned} & \text { Turn-On Time (See Figures } 1 \text { and 2) } \\ & \left(I_{D(o n)}=6.0 \mathrm{mAdc}\right) \\ & \left(\mathrm{I}_{\mathrm{D}(\mathrm{on})}=3.0 \mathrm{mAdc}\right) \end{aligned}$ | MPF4392 <br> MPF4393 | $\mathrm{t}_{\mathrm{on}}$ | - | $\begin{aligned} & 4.0 \\ & 6.5 \end{aligned}$ | $\begin{aligned} & 15 \\ & 15 \end{aligned}$ | ns |
| Turn-Off Time (See Figures 3 and 4) $\begin{aligned} & \left.\left(\mathrm{VGS}_{\mathrm{Gf}} \mathrm{off}\right)=7.0 \mathrm{Vdc}\right) \\ & \left(\mathrm{V}_{\mathrm{GS}(\mathrm{off})}=5.0 \mathrm{Vdc}\right) \end{aligned}$ | $\begin{aligned} & \text { MPF4392 } \\ & \text { MPF4393 } \end{aligned}$ | $t_{\text {off }}$ | - | $\begin{aligned} & 20 \\ & 37 \end{aligned}$ | $\begin{aligned} & 35 \\ & 55 \end{aligned}$ | ns |

1. Pulse Test: Pulse Width $\leq 300 \mu \mathrm{~s}$, Duty Cycle $\leq 3.0 \%$.

TYPICAL SWITCHING CHARACTERISTICS


Figure 1. Turn-On Delay Time


Figure 3. Turn-Off Delay Time


Figure 2. Rise Time


Figure 4. Fall Time

NOTE 1
The switching characteristics shown above were measured using a test circuit similar to Figure 5. At the beginning of the switching interval, the gate voltage is at Gate Supply Voltage $\left(-\mathrm{V}_{\mathrm{GG}}\right)$. The Drain-Source Voltage ( $\mathrm{V}_{\mathrm{DS}}$ ) is slightly lower than Drain Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}$ ) due to the voltage divider. Thus Reverse Transfer Capacitance ( $\mathrm{C}_{\mathrm{rss}}$ ) or Gate-Drain Capacitance ( $\mathrm{C}_{\mathrm{gd}}$ ) is charged to $V_{G G}+V_{D S}$.

During the turn-on interval, Gate-Source Capacitance ( $\mathrm{Cgs}_{\mathrm{gs}}$ ) discharges through the series combination of $\mathrm{R}_{\text {Gen }}$ and $\mathrm{R}_{\mathrm{K}} \cdot \mathrm{C}_{\mathrm{gd}}$ must discharge to $\mathrm{V}_{\mathrm{DS}(\text { on })}$ through $\mathrm{R}_{\mathrm{G}}$ and $\mathrm{R}_{\mathrm{K}}$ in series with the parallel combination of effective load impedance ( $\mathrm{R}_{\mathrm{D}}^{\prime}$ ) and Drain-Source Resistance ( $\mathrm{r}_{\mathrm{ds}}$ ). During the turn-off, this charge flow is reversed.

Predicting turn-on time is somewhat difficult as the channel resistance $r_{d s}$ is a function of the gate-source voltage. While $C_{g s}$ discharges, $V_{G S}$ approaches zero and $r_{d s}$ decreases. Since $C_{g d}$ discharges through $\mathrm{r}_{\mathrm{d}}$, turn-on time is non-linear. During turn-off, the situation is reversed with $\mathrm{r}_{\mathrm{ds}}$ increasing as $\mathrm{C}_{\mathrm{gd}}$ charges.

The above switching curves show two impedance conditions: 1) $R_{K}$ is equal to $R_{D}{ }^{\prime}$ which simulates the switching behavior of cascaded stages where the driving source impedance is normally the load impedance of the previous stage, and 2) $R_{K}=0$ (low impedance) the driving source impedance is that of the generator.


Figure 7. Typical Capacitance


Figure 9. Effect of Temperature On Drain-Source On-State Resistance


Figure 10. Effect of IDss On Drain-Source Resistance and Gate-Source Voltage

## NOTE 2

The Zero-Gate-Voltage Drain Current ( $\mathrm{I}_{\mathrm{DSS}}$ ), is the principle determinant of other J-FET characteristics. Figure 10 shows the relationship of Gate-Source Off Voltage ( $\mathrm{V}_{\mathrm{GS} \text { (off) }}$ ) and Drain-Source On Resistance ( $\mathrm{r}_{\mathrm{ds}(o n)}$ ) to $\mathrm{I}_{\text {DSS. }}$. Most of the devices will be within $\pm 10 \%$ of the values shown in Figure 10. This data will be useful in predicting the characteristic variations for a given part number.

## For example:

Unknown
$\mathrm{r}_{\mathrm{ds}(\mathrm{on})}$ and $\mathrm{V}_{\mathrm{GS}}$ range for an MPF4392
The electrical characteristics table indicates that an MPF4392 has an $\mathrm{I}_{\text {DSS }}$ range of 25 to 75 mA . Figure 10 shows $\mathrm{r}_{\mathrm{ds}(\text { on })}=52 \Omega$ for $\mathrm{I}_{\text {DSS }}=25 \mathrm{~mA}$ and $30 \Omega$ for $\mathrm{I}_{\mathrm{DSS}}$ 75 mA . The corresponding $\mathrm{V}_{\mathrm{GS}}$ values are 2.2 V and 4.8 V .

MPF4392, MPF4393

## PACKAGE DIMENSIONS

TO-92 (TO-226)
CASE 29-11
ISSUE AM


BENT LEAD
TAPE \& REEL
AMMO PACK


SECTION X-X

NOTES:
DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH
3. CONTOUR OF PACKAGE BEYOND DIMENSIONR IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|  | INCHES |  | MILLIMETERS |  |
| :---: | ---: | ---: | ---: | ---: |
| DIM | MIN | MAX | MIN | MAX |
| A | 0.175 | 0.205 | 4.45 | 5.20 |
| B | 0.170 | 0.210 | 4.32 | 5.33 |
| C | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.016 | 0.021 | 0.407 | 0.533 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| H | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.015 | 0.020 | 0.39 | 0.50 |
| K | 0.500 | --- | 12.70 | --- |
| L | 0.250 | --- | 6.35 | --- |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| P | --- | 0.100 | --- | 2.54 |
| R | 0.115 | --- | 2.93 | --- |
| V | 0.135 | --- | 3.43 | --- |

STYLE 5:
PIN 1. DRAIN
2. SOURCE
3. GATE

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN $P$ AND BEYOND DIMENSION K MINIMUM.

|  | MILLIMETERS |  |
| :---: | :---: | :---: |
| DIM | MIN | MAX |
| A | 4.45 | 5.20 |
| B | 4.32 | 5.33 |
| C | 3.18 | 4.19 |
| D | 0.40 | 0.54 |
| G | 2.40 | 2.80 |
| J | 0.39 | 0.50 |
| K | 12.70 | --- |
| N | 2.04 | 2.66 |
| P | 1.50 | 4.00 |
| R | 2.33 | --- |
| $\mathbf{V}$ | 3.43 | --- |

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